

# Exploring synergies between electronic material measurements and modeling

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S12 – Electronic Materials Applications in 5G Telecommunications



# Polish high-tech SME - 23 years on the world's market

## Business branches presented annually at IEEE IMS Show

**QuickWave Electromagnetic Design** 

& simulation software,

3D & BOR 2D & multiphysics modules based on 300+ publications by:

prof.W.Gwarek, IEEE Fellow, DML, Pioneer Award dr.M.Celuch, President of QWED

> DIPLOMA Eureka!

BELGIAN AND INTERNATIONAL TRADE FA

Madena menuesta - Pola di Bassali i fushiki Padena ikenasi Unienty di Tabatiga - ficata di Sortegan ad Memoliki Tabatiga - ficata di





届国际发明展览会区

applications of chiral materials  $\rightarrow$  EM validation of mixing rules

**FP6 SOCOT** – development and validation of an optimal

FP6 CHISMACOMB - development, modelling, and

methodology for overlay control in semiconductor industry, for

**R&D** projects

the 32 nm technology node and beyond.

Eureka E! 2602 MICRODEFROST MODEL – innovative software-based product development tool for simulating and optimising heating and defrosting processes in microwave ovens



FP7 HIRF SE (High Intensity Radiated Field Synthetic Environment) - numerical modelling framework for aeronautic industry



Eureka FOODWASTE – developing new microwave treatment system for high water content waste



ERA-NET MNT NACOPAN - applications and modelling of nano-conductive polymer composites



NGAM2 – designing an industrial device for thermal bonding of bituminous surfaces with the aid of microwave heating



MMAMA (Microwave Microscopy for Advanced and Efficient Materials Analysis and Production) - accelerating the development of high efficiency solar cells through application and enhancement of material measurement techniques



Test-fixtures for precise material measurements based on 300+ publications by prof.J.Krupka, IEEE Fellow



### **Consultancy & design services** based on EM expertise & tools

team of 10+engineers, 4 PhDs, 2 Profs key areas: MW power appliances, customised resonators, antennas & feeds



## My message for today (sorry if sounds trivial!)

Modelling & measurements are **not** two separate worlds. Exploring synergies is where QWED sees the future.



## Electromagnetic modelling and design – antennas & feed systems

## QuickWave-3D:

#### world's recognised 3D EM simulation tool



Balanced antipodal Vivaldi antenna & 3D radiation pattern at 10 GHz.





Aperture-coupled patch antenna on uniplanar photonic bandgap substrate & its radiation pattern at 12 GHz.



QuickWave 3D results at NRAO, see: ALMA Memos 381, 343, 325, 278.



Pyramidal horn antenna for military surveillance measured (courtesy prof.B.Stec) & simulated patterns

#### QuickWave BOR:

#### unique on the market & ultrafast tool for axisymmetrical structures



W.Gwarek, *IEEE Trans. MTT*: vol.33 Oct.1985; vol.36 Feb.& Apr. 1988. **Key developments:** 

M.Celuch & W.Gwarek, *IEEE Trans. MTT*, vol.43 Sep.1995, vol.41 May1993, vol.45 May1997, vol.51 Aug.2003; *EuMC* 1991-1997; *IEEE IMS* 2001-2004. **Reviews:** *IEEE Microwave Mag.*, Dec.2008 & Apr.2010; *IJMPEE* vol.41 2007.

## Electromagnetic modelling & design – high MW power applications



ប<sup>100</sup>

Time [s]

and leakage preventing chokes: designed, manufactured, tested B.Salski et al., *IEEE MTT Trans.*, vol.65, Sep.2017.

System of three MW power applicators with feeding system

# Acknowledgements

The work presented has received funding from the

European Union's Horizon 2020

research and innovation programme (H2020-NMBP-07-2017)



under grant agreement

MMAMA n°761036.

(website: <u>www.mmama.eu</u>)





THE EUROPEAN INFORMATION TECHNOLOGY PRIZE Simulations were o

Simulations were conducted with QuickWave EM software, developed & commercialised by QWED.

#### The original designs of QWED resonators for material measurements were from Prof. Jerzy Krupka, e.g.:

J. Krupka, A. P. Gregory, O. C. Rochard, R. N. Clarke, B. Riddle, and J. Baker-Jarvis, "Uncertainty of complex permittivity measurements by split-post dielectric resonator technique", *J. Eur. Ceramic Soc.*, vol. 21, pp. 2673-2676, 2001.

J. Krupka and J. Mazierska, "Contactless measurements of resistivity of semiconductor wafers employing single-post and split-post dielectric-resonator techniques," *IEEE Trans. Instr. Meas.*, vol. 56, no. 5, pp. 1839-1844, Oct. 2007.

#### Microwave heating scenarios & concepts by Per O. Risman, Microtrans AB & Malardalen University, Sweden.

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Winner

# Outline

- Electromagnetic modelling as a basis for precise material measurements
- Split-post dielectric resonator (SPDR): why it has become a standard
- Other types of dielectric resonators
- SPDR measurements of larger surfaces & resolution enhancement
- "Transfer of technology" from other application & the applications themselves:
  - **o** "near field imaging" from MW heating
  - $\circ~$  multiphysics modelling of MW heating
  - common CAD interfaces
  - o sub-cellular models in FDTD (hints)
  - "near field imaging" in antenna design
- Modelling of SMM tips for material measurements at nano-scale
  - **o** unconventional (but constructive) definitions of impedance and S-matrix
- Conclusions

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## Dielectric resonator methods for material measurements

metal enclosure

dielectric resonator auxiliary dielectrics measured sample

SUT of  $\varepsilon_s = \varepsilon_s' - j \varepsilon_s''$  is inserted into DR: resonant frequency changes from  $f_e$  to  $f_s$ Q-factor changes from  $Q_e$  to  $Q_s$ .

$$\frac{f_e - f_s}{f_e} \approx \frac{h}{2C} \iint_{S} \left[ \varepsilon'_s \left( x, y \right) - 1 \right] \left| E \left( x, y \right) \right|^2 dS$$

$$\frac{1}{Q_s} - \frac{1}{Q_e} \approx \frac{h}{C} \iint_{S} \varepsilon_s^{"}(x, y) E^2(x, y) dS$$

$$C = \iiint_{V} \left| E\left(x, y\right) \right|^{2} dV$$

field assumed invariant in *z*-direction S is called the DR's *head* sign ≈ reflects field patern changes caused by SUT

calibration (only once, upon manufacturing!) minimises efects of: field variation in z field changes due to SUT manufactruing tolerances

Most popular example: Split-Post Dielectric Resonator

SPDR

cavity

axis of symmetry



## **Fields in SPDR**

## **E-field**

## **H-field**





- resonant mode with EM fields mostly confined in and between those ceramic posts → minimial losses in metal enclosure
- H-field is only vertical at the side wall of the enclosure  $\rightarrow$  only circumferential currents in side wall  $\rightarrow$  no radiation through slot
- E-field tangential to SUT → air slots between SUT and posts have negligible effect
- easy SUT insertion through slot, no dismatling, NDT method
- all EM energy injected through the coupling loops in contained within in the SPDR "head" (inside the enclosure)
- an estimated 95% of energy confined in and between the ceramic posts
- calibration only once, at manufacturing

# Accuracy of SPDR measurements



#### h=0.4 mm 5.2 f(GHz) h=0.2 mm 5 4.8 h=0.8 mm 4.6 h=1.2 mm 4.4 h=1.6 mm 4.2 h=2 mm 10 100 3

accuracy for  $\varepsilon$  typically 0.3% measurable losses tan $\delta \sim 6 \ 10^{-5}$ 

## → European Standard: IEC 61189-2-721:2015

**Limitations** (which we are currently addressing...):

- SUT thickness slot size 0.6..6 mm
- SUT lateral min size ("absolute" EM constraint) 14..120 mm ٠
- spatial resolution 14..120 mm
- SUT lateral max size (mechanical construction) 40..150 mm Orlando, FL, 23 January 2020

 $\Delta \varepsilon / \varepsilon = \pm (0.0015 + \Delta h/h)$ Δtanδ=±2\*10<sup>-5</sup> or ±0.03\*tanδ whichever is higher

	Conductivity $[1/(\Omega m)]$	Resistivity [Ω cm]	Surface resistivity $[\Omega/sq]$
Range od SPDR applications	from 10-2 to 1	from 10 <sup>2</sup> to 10 <sup>4</sup>	from 5 10 <sup>3</sup> to 10 <sup>6</sup>
Range of SiPDR applications	from 1 to 10 <sup>7</sup>	from 10 <sup>-5</sup> to 10 <sup>2</sup>	from 2 10-4 to 5 10 <sup>3</sup>
Sapphire	> 5 106		

# Other types of dielectric resonators (TE01 $\delta$ )









single-post

resistive sheets

cavity resonating SUT ultra-low-loss SUTs





sapphire

metal SUTs





liquids & powders can also heat

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# Surface scanning with SPDR

**Obviating the limitations:** 

- SUT thickness slot size 0.6..6 mm
- SUT lateral min size ("absolute" EM constraint) 14..120 mm
- spatial resolution 14..120 mm
- SUT lateral max size 40..150 mm

## manual scanner for large panes of glass (MW oven window)



- $\rightarrow$  increase by decreasing frequency
- → scanning & postprocessing
- → scanning & postprocessing
- → increase by change of mechanical construction

### automatic scanner

semiconductor wafers, composites, organic samples



## Automatic surface scanning with SPDR



working with QWED Q-Meter

**ЛЛГ** ммама



## working with FieldFox (Keysight hand-held VNA)



## samples from MateriaNova



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# **Resolution enhancement for SPDR imaging**

→ Parameters are "averaged" within DR head but we know the field pattern

E-field in our 10 GHz SPDR as simulated in QuickWave and tranferred onto the scanning grid:







0.1

0.05

0

20

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# **Resolution enhancement for SPDR imaging**

Consider the head meshed into  $(2K + 1) \times (2L + 1)$  cells whose center with  $E_T(0,0)$  is placed at cell (m,n) the scan. For clarity, assume that the mesh is equidistant of raster a (a = 1mm in Fig. 1). The measured energy change due to the SUT is:

$$\Delta W_{mn} = \frac{a^2 h}{2} \sum_{k=-K}^{K} \sum_{l=-L}^{L} \left[ \varepsilon_s'(m+k,n+l) - 1 \right] E_T^2(k,l)$$

Arranging the 2D array of  $\Delta W_{mn}$  into a 1D vector W of elements  $\Delta W_i$ ,  $i=(n-1)^*M+m$ ,  $i=1,..,M^*N$ , and similarly the 2D array of permittivities  $p_{s,mn}=(\varepsilon_s'-1)_{mn}$  into vector P:

[W] = [T] [P]

Matrix T is generated in such a way that element  $t_{rs}$  in row r and column s is equal to :

 $-|E_T(k, I)|^2$  for s = r + k + MI for k = -K..+K and I = -L...+L

- 0 for *s* not obeying the above condition.

 $[P] = [T]^{-1} [W]$ 

Matrix T is large,  $M^*N \times M^*N$ , but sparse and has a banded structure.

## Space-domain, not Fourier - domain

## MATLAB experiments with virtual scans: matrix inversion of exact data & with noise



10 20 30 40 50

16

Filter 3

10 20

10 20

30 40 50

30 40 50

50

40

30

20

10

2

3

2

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# **Singular Value Decomposition**





scan area 41x41mm
=> matrix 1681x1681 (step 1mm)
SUT laminate Rogers R4003 h=20mils (0.508 mm)
SUT size 15x15 mm
scan saved in Gwyddion format





# MATLAB experiments with laboratory scans: experimenting with SVD parameters



















30

40

10 20 30

10 20

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How much is the E-field pattern influenced by SUT?

→ application of "near field imaging" in QuickWave



# 10 GHz SPDR model in QW-AddIn for Autodesk<sup>®</sup> Inventor<sup>®</sup> Software (common environment for modelling & manufacturing)

How much is the E-field pattern influenced by SUT?

→ application of "*near field imaging*" in QuickWave





#### with SUT

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### How much is the E-field pattern influenced by SUT?

→ application of "*near field imaging*" in QuickWave



Curently field subtraction performed on saved fields. Parallel running of 2 scenarios under development.

How much is the E-field pattern influenced by SUT?

→ application of "*near field imaging*" in QuickWave



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# Advanced near-field imaging functionality

Separation of incident and diffracted fields (option implemented per request of P.O.Risman, Malardalen University)



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\* https://sites.utexas.edu/austinmanaustinwomanmodels/

## Accurate modelling of coupled electromagnetic-thermal problems

## **Application to microwave processing of materials**



Frequency (GHz)

\* Considered by M.Celuch, P.Kopyt & M. Olszewska-Placha in eds. M. Lorence, P. S. Pesheck, U. Erle, *Development of packaging and products for use in microwave ovens*, 2nd Ed. Elsevier in print.

## Multiphysics modelling: temperature-dependent materials



# Multiphysics modelling: *Collect Data* in *Grid Search*

Collect Data of S11 and dissipated power density in potato heated in MW oven, as text files and GUI



[S11] (GS=3) F= 8.0000 [GHz] |S11| (GS=4) F= 8.0000 [GHz]





# Unusual QuickWave applications

-10

-15

-20

-25 -30

-35

-40<u></u>

**\$FLIR** 

(dB)

S<sub>11</sub>

#### High power applicator for $\mu$ W treatment of bituminous surfaces aiming at road repair

Simulated & measured reflection coefficient

2.1 2.2 2.3 2.4 2.5 2.6 2.7 2.8 2.9 3

Frequency (GHz)

Measured temperature distribution

156.8 0

154 5 Bx1

#### Challenges

High dissipation of  $\mu W$  power in road surface

Safety issues – prevention of EM energy leakage





System of three MW power applicators with feeding system and leakage preventing chokes: designed, manufactured, tested





Exposure levels @ 0.5m from applicator

**Below standardized limits** 

0.7

Lield 0.5



2445 2450 2455 2460 2465 Frequency (MHz)

## High power applicator with a system of chokes preventing $\mu$ W energy leakage

In front

B. Salski, M. Olszewska-Placha, T. Karpisz, J. Rudnicki, W. Gwarek, M. Maliszewski, A. Zofka, J. Skulski, "Microwave applicator for thermal treatment of bituminous surfaces", IEEE MTT Trans., vol. 65, no. 99, pp. 1-9, 2017

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## Advanced optimisation and parameters sweep workflows





Microwave applicator for thermal treatment of bituminous surfaces

B.Salski et al., *IEEE MTT Trans.*, vol.65, Sep.2017. Orlando, FL, 23 January 2020 Internal optimisation

Optimisation with external tools – commercial and inhouse

Typical, software predefined optimization objectives, e.g. Sparameters, Radiation patterns (incl. fit under user-defined radiation envelope), etc.

#### All simulation available objectives,

e.g. power dissipated, shielding effectiveness, radiation efficiency, etc., through external data-extraction application

Simulation results saved to file



Optimiser – internal or external



# Dedicated user interfaces for parametrised project creation



*Curiosity: export of CAD files from "old" QW-Editor for further manufacturing is reported by our user.*  CAD tool - FreeCAD based Free of charge, No licences, No time restrictions, No project limitations

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EMA 2020 S12

Import/export to e.g. \*.step, \*.iges& \*.dxf

## Conclusions

## With this talk I seek collaborations:

on the development of:

## on behalf of:

- material measurement test-fixtures,
- applicators for processing of materials,
- software models & workflows for material modelling.

- **QWED** team,
- our European projects MMAMA, NanoBat,
- members of broader EU initiatives, e.g. European Materials Modelling Council.

# **THANK YOU!**







